## DIGITRON <br> SEMICONDUCTORS

SD241
30 AMP SCHOTTKY RECTI FIERS
ELECTRI CAL CHARACTERISTICS

| Characteristics | Symbol | Value | Test Conditions |
| :---: | :---: | :---: | :---: |
| Working peak reverse voltage | $\mathrm{V}_{\text {RWM }}$ | 35 V |  |
| Repetitive peak reverse voltage | $\mathrm{V}_{\text {RRM }}$ | 35 V |  |
| Standard average forward current | $\mathrm{I}_{\text {F(AV) }}$ | 30A | $\mathrm{T}_{\mathrm{C}}=148^{\circ} \mathrm{C}$, square wave, $\mathrm{R}_{\text {打 }}=1.4^{\circ} \mathrm{C} / \mathrm{W}$ |
| Reverse average forward current | $\mathrm{I}_{\mathrm{F}(\mathrm{AV})}$ | 30A | $\mathrm{T}_{\mathrm{C}}=132^{\circ} \mathrm{C}$, square wave, $\mathrm{R}_{\text {ө } \mathrm{C}}=2.2^{\circ} \mathrm{C} / \mathrm{W}$ |
| Maximum surge current | $\mathrm{I}_{\text {FSM }}$ | 600A | 8.3 ms , half-sine, $\mathrm{T}_{\mathrm{J}}=175^{\circ} \mathrm{C}$ |
| Maximum repetitive peak reverse current | $\mathrm{I}_{\mathrm{R} \text { (OV) }}$ | 2A | $\mathrm{f}=1 \mathrm{KHz}, 25^{\circ} \mathrm{C}, 1 \mu \mathrm{sec}$ square wave |
| Maximum peak forward voltage | $\mathrm{V}_{\text {FM }}$ | 0.57 V | $\mathrm{I}_{\mathrm{FM}}=30 \mathrm{~A}, \mathrm{~T}_{\mathrm{J}}=175^{\circ} \mathrm{C}^{*}$ |
| Maximum peak forward voltage | $\mathrm{V}_{\text {FM }}$ | 0.70 V | $\mathrm{I}_{\mathrm{FM}}=30 \mathrm{~A}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}^{*}$ |
| Maximum peak reverse current | $\mathrm{I}_{\text {RM }}$ | 25 mA | $\mathrm{V}_{\text {RRM }}, \mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}^{*}$ |
| Maximum peak reverse current | $\mathrm{I}_{\mathrm{RM}}$ | 1.5 mA | $\mathrm{V}_{\text {RRM }}, \mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |
| Typical junction capacitance | $\mathrm{C}_{\text {J }}$ | 1350pF | $\mathrm{V}_{\mathrm{R}}=5.0 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |

*Pulse test: pulse width $300 \mu \mathrm{sec}$, duty cycle $2 \%$

## THERMAL CHARACTERISTICS

| Characteristics | Symbol | Test Conditions |
| :--- | :---: | :---: |
| Storage temperature range | $\mathrm{T}_{\text {stg }}$ | $-65^{\circ}$ to $175^{\circ} \mathrm{C}$ |
| Operating junction temperature range | $\mathrm{T}_{\mathrm{J}}$ | $-65^{\circ}$ to $175^{\circ} \mathrm{C}$ |
| Standard maximum thermal resistance | $\mathrm{R}_{\text {ө } \mathrm{C}}$ | $1.4^{\circ} \mathrm{C} / \mathrm{W}$ junction to case |
| Reverse maximum thermal resistance | $\mathrm{R}_{\text {өر } \mathrm{C}}$ | $2.2^{\circ} \mathrm{C} / \mathrm{W}$ junction to case |
| Typical thermal resistance (greased) | $\mathrm{R}_{\ominus \mathrm{Cs}}$ | $0.5^{\circ} \mathrm{C} / \mathrm{W}$ case to sink |

## MECHANI CAL CHARACTERISTICS

| Case | TO-3 |
| :--- | :--- |
| Marking | Alpha numeric |
| Pin out | See below |



|  | MO-3 |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Inches |  | Millimeters |  |
|  | Min | Max | Min | Max |
| CD | - | 0.875 | - | 22.220 |
| CH | 0.250 | 0.380 | 6.860 | 9.650 |
| HT | 0.060 | 0.135 | 1.520 | 3.430 |
| BW | - | 1.050 | - | 26.670 |
| HD | 0.131 | 0.188 | 3.330 | 4.780 |
| LD | 0.038 | 0.043 | 0.970 | 1.090 |
| LL | 0.312 | 0.500 | 7.920 | 12.700 |
| BL | 1.550 | REF | 39.370 | REF |
| MHS | 1.177 | 1.197 | 29.900 | 30.400 |
| PS | 0.420 | 0.440 | 10.670 | 11.180 |
| S1 | 0.655 | 0.675 | 16.640 | 17.150 |

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).
Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

# DIGITRON SEMICONDUCTORS 

Figure 1
Typical Forward Characteristics


Figure 2
Typical Reverse Characteristics


Figure 3
Typical Junction Capacitance


Figure 4
Forward Current Derating - Standard Polarity


Figure 5
Forward Current Derating - Reverse Polarity


